



EGP20A thru EGP20G

Glass Passivated Junction Fast Efficient Rectifiers
Reverse Voltage 50 to 400 Volts Forward Current 2.0 Amperes

Features

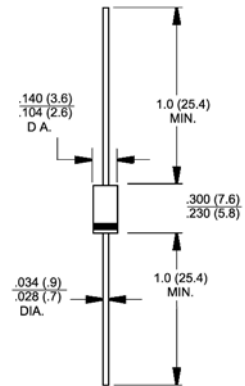
- ◆ Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- ◆ Cavity-free glass passivated junction
- ◆ Ultrafast recovery time for high efficiency
- ◆ Low forward voltage, high current capability
- ◆ Low leakage current
- ◆ High surge current capability
- ◆ High temperature metallurgically bonded construction
- ◆ High temperature soldering guaranteed:
300°C/10 seconds, 0.375" (9.5mm) lead length,
5 lbs. (2.3kg) tension



DO-204AC (DO-15)

Mechanical Data

- ◆ Case: JEDEC DO-204AC, molded plastic over solid glass body
- ◆ Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- ◆ Polarity: Color band denotes cathode end
- ◆ Mounting Position: Any
- ◆ Weight : 0.014 ounce, 0.395 gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

| Parameter | Symbol | EGP 20A | EGP 20B | EGP 20C | EGP 20D | EGP 20F | EGP 20G | Unit |
|---|------------------------------------|--------------|---------|---------|---------|---------|---------|--------------------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 150 | 200 | 300 | 400 | Volts |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 105 | 140 | 210 | 280 | Volts |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 150 | 200 | 300 | 400 | Volts |
| Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A=55^\circ\text{C}$ | $I_{F(AV)}$ | 2.0 | | | | | | Amps |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | 75.0 | | | | | | Amps |
| Maximum instantaneous forward voltage at 2.0A | V_F | 0.95 | | | | 1.25 | | Volts |
| Maximum DC reverse current at rated DC blocking voltage @ $T_A=25^\circ\text{C}$ @ $T_A=125^\circ\text{C}$ | I_R | 5.0 100 | | | | | | μA |
| Maximum reverse recovery time at $I_R=0.5\text{A}$, $I_F=1.0\text{A}$, $I_R=0.25\text{A}$ | t_{rr} | 50 | | | | | | nS |
| Typical junction capacitance at 4.0V, 1MHz | C_J | 70.0 | | | | 45.0 | | pF |
| Typical thermal resistance (Note 1) | $R_{\theta JA}$ $R_{\theta JL}$ | 40.0 15.0 | | | | | | $^\circ\text{C/W}$ |
| Operating junction and storage temperature range | T_J, T_{STG} | -55 to +150 | | | | | | $^\circ\text{C}$ |

Notes: 1. Thermal resistance from junction to ambient, and from junction to lead at 0.375" (9.5mm) lead length, P.C.B. mounted

RATINGS AND CHARACTERISTIC CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Maximum Forward Current Derating Curve

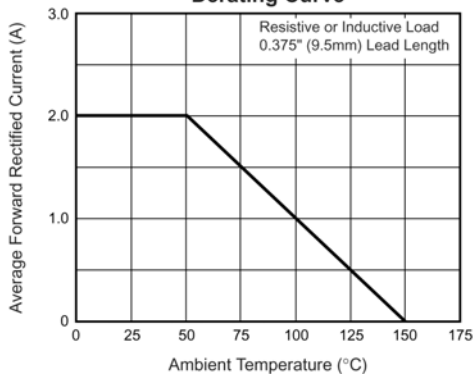


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

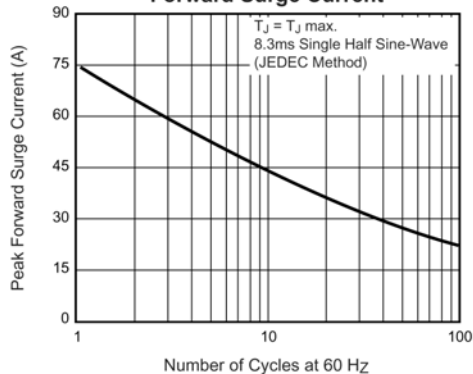


Fig. 3 – Typical Instantaneous Forward Characteristics

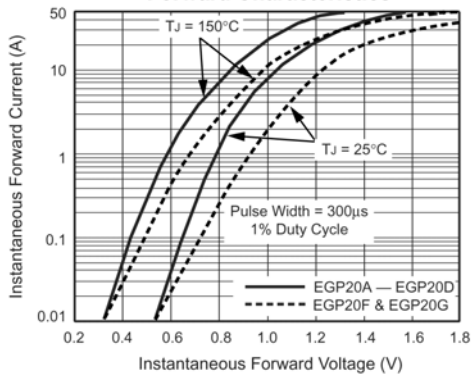


Fig. 4 – Typical Reverse Characteristics

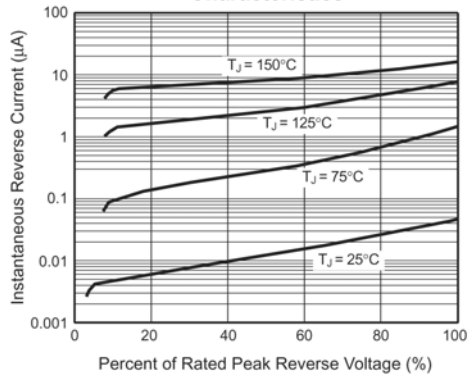


Fig. 5 – Typical Junction Capacitance

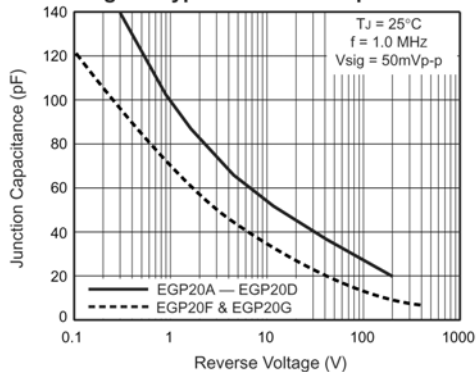


Fig. 6 – Typical Transient Thermal Impedance

